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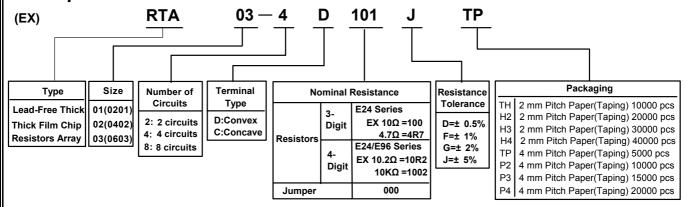
Thick Film Chip Resistors Array Product Specification

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1 Scope:

This specification is applicable to lead and halogen free RTA series thick film chip resistors array •

2 Explanation Of Part Numbers:



3 General Specifications:

71				T.C.R. (ppm/°C)	D(± 0.5%)	esistance Rang F(± 1%)	e G(± 2%) J(± 5%)	Number of	Number of	JUMPER (0Ω) Rated	JUMPER (0Ω) Resistance
	at 70°C	Voltage	Voltage		E-24 · E-96	E-24 · E-96	E-24	Terminals	Resistors	Current	Value
DT404 0D				± 500			$3\Omega \leq R < 10\Omega$				
RTA01-2D (0201)	1/32W	12.5V	25V	± 300			$10\Omega\!\leq\!R\!<\!1K~\Omega$	4	2	0.5A	50m Ω Max.
, ,				± 200			$1K\Omega \leq R \leq 1\;M\Omega$				
RTA02-2D	1/16W	25V	50V	± 300		$1\Omega \leq R < 10\Omega$	$1\Omega \leq R < 10\Omega$	4	2	1A	50m Ω Max.
(0402)	17 1011	201		± 200		$10\Omega\!\leq\!R\!\leq\!1M\Omega$	$10\Omega\!\leq\!R\!\leq\!1M\Omega$	·	_	.,,	oom zzmax.
RTA03-2D (0603)	1/16W	50V	100V	± 200		$10\Omega\!\leq\!R\!\leq\!1M\Omega$	$1\Omega\!\leq\!R\!\leq\!10M\Omega$	4	2	1A	50m Ω Max.
RTA02-4D	1/16W	25V	50V	± 300		$1\Omega \leq R < 10\Omega$	$1\Omega \leq R < 10\Omega$	8	4	1A	50mΩMax.
(0402)	17 10 00	250	30 V	± 200		$10\Omega\!\leq\!R\!\leq\!1M\Omega$	$10\Omega{\leq}R{\leq}1M\Omega$			IA	John Mark
RTA02-4C	1/16W	25V	50V	± 400		$1\Omega \leq R < 10\Omega$	$1\Omega \leq R < 10\Omega$	8	4	1A	50m Ω Max.
(0402)	17 10 00	201	301	± 200		$10\Omega\!\leq\!R\!\leq\!1M\Omega$	$10\Omega{\le}R{\le}1M\Omega$	8	4	IA	JOHN SZIVIAX.
RTA03-4D (0603)	1/16W	50V	100V	± 200	22Ω≦R≦470KΩ	$1\Omega \le R \le 10M\Omega$	$1\Omega \le R \le 10M\Omega$	8	4	1A	50m Ω Max.
RTA03-4C (0603)	1/16W	50V	100V	± 200		$1\Omega \le R \le 1M\Omega$	$1\Omega \le R \le 10M\Omega$	8	4	1A	50m Ω Max.
RTA02-8D (0402)	1/16W	25V	50V	± 250		$10\Omega \leq R \leq 1M\Omega$	$1\Omega \leq R \leq 1M\Omega$	16	8	1A	50m Ω Max.
RTA03-8C (0603)	1/16W	50V	100V	± 200		$1\Omega \le R \le 1M\Omega$	$1\Omega \le R \le 10M\Omega$	16	8	1A	50m Ω Max.
RTA03-2C (0603)	1/16W	50V	100V	± 200		$1\Omega \le R \le 1M\Omega$	$1\Omega \le R \le 10M\Omega$	4	2	1A	50m Ω Max.
RTA02-2C	1/16W	25V	50V	± 650		$3\Omega \leq R < 10\Omega$	$3\Omega \leq R < 10\Omega$	4	2	1A	50m Ω Max.
(0402)				± 250		$10\Omega\!\leq\!R\!\leq\!1M\Omega$	$10\Omega\!\leq\!R\!\leq\!1M\Omega$	•	_	., ,	
Operating Temperature Range			nge	_55°C ~ +155°C							

Approved

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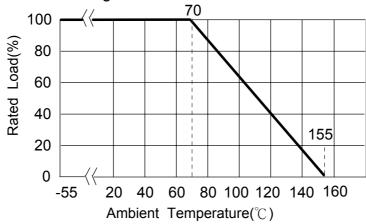
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3.1 Power Derating Curve:

Operating Temperature Range : - 55~155 ℃

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with figure below.



3.2 Voltage Rating:

Rated Voltage: The resistor shall have a DC continuous working voltage or a rms. AC continuous working voltage at commercial-line frequency and wave form corresponding to the power rating, as determined from the following:

$$E = \sqrt{R \times P}$$

E= Rated voltage (v)

P= power rating (w)

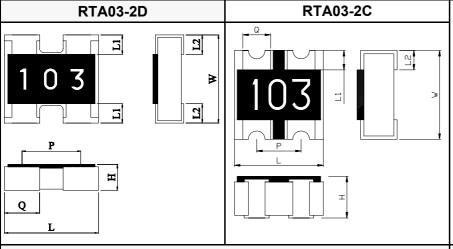
R= Nominal resistance(Ω)

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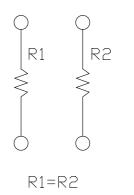
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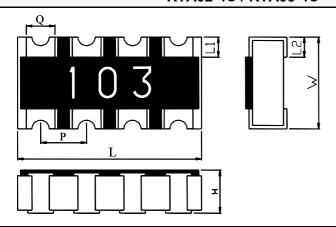
4 Dimensions: (mm)



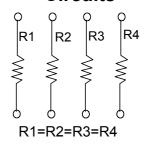


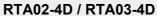


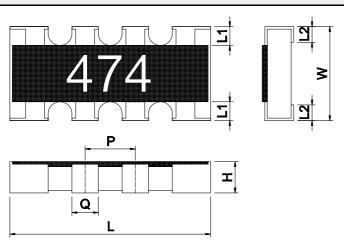
RTA02-4C / RTA03-4C



Circuits







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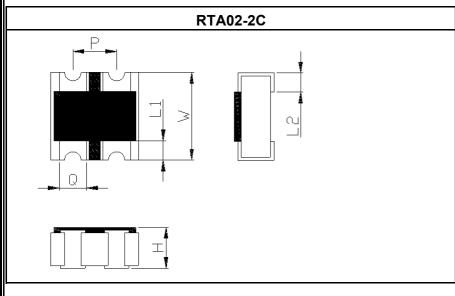
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RALEC IE-SP-011 Document No. **Thick Film Chip Resistors Array** Released Date 2011/02/20 旺 詮 **Product Specification** Page No. 4/21 RTA02-8D / RTA03-8C **Circuits** Q R1 = R2= R3 = R4 = R5 = R6 = R7 = R8 RTA01-2D / RTA02-2D Circuits R1=R2 0

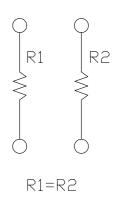
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Circuits



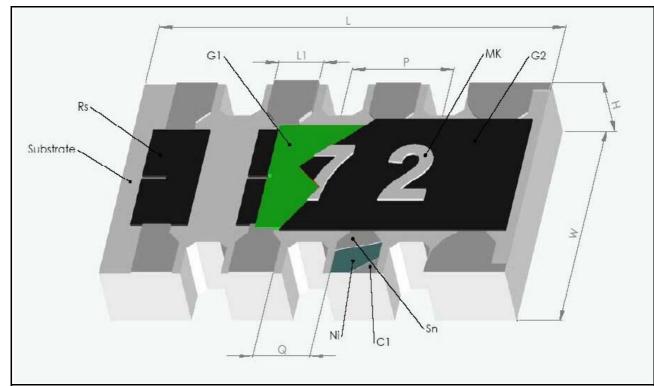
型式 尺寸	L	w	Н	L1	L2	Р	Q
RTA01-2D (0201)	0.80± 0.10	0.60± 0.10	0.30± 0.05	0.15± 0.10	0.15± 0.05	(0.50)	0.35± 0.10
RTA02-2D (0402)	1.00± 0.10	1.00± 0.10	0.30± 0.05	0.15± 0.10	0.25± 0.10	(0.67)	0.33± 0.10
RTA03-2D (0603)	1.60± 0.15	1.60± 0.15	0.45± 0.10	0.30± 0.15	0.30± 0.15	(0.80)	0.60± 0.10
RTA02-4D (0402)	2.00± 0.10	1.00± 0.10	0.40± 0.10	0.20± 0.10	0.25± 0.10	(0.50)	0.30± 0.10
RTA02-4C (0402)	2.00± 0.10	1.00± 0.10	0.40± 0.10	0.15± 0.10	0.25± 0.10	(0.50)	0.30± 0.10
RTA03-4D (0603)	3.20± 0.20	1.60± 0.15	0.50± 0.10	0.30± 0.15	0.30± 0.15	(0.80)	0.50± 0.10
RTA03-4C (0603)	3.20± 0.15	1.60± 0.15	0.55± 0.10	0.35± 0.15	0.45± 0.15	(0.80)	0.50± 0.10
RTA02-8D (0402)	4.00± 0.20	1.60± 0.10	0.40± 0.10	0.30± 0.15	0.30± 0.10	(0.50)	0.25± 0.10
RTA03-8C (0603)	6.40± 0.20	1.60± 0.20	0.55± 0.10	0.30± 0.15	0.40± 0.15	(0.80)	0.50± 0.10
RTA03-2C (0603)	1.60± 0.15	1.60± 0.15	0.55± 0.10	0.30± 0.15	0.40± 0.15	(0.80)	0.50± 0.10
RTA02-2C (0402)	1.00± 0.10	1.00± 0.10	0.30± 0.10	0.18± 0.10	0.25± 0.10	(0.50)	0.30± 0.10

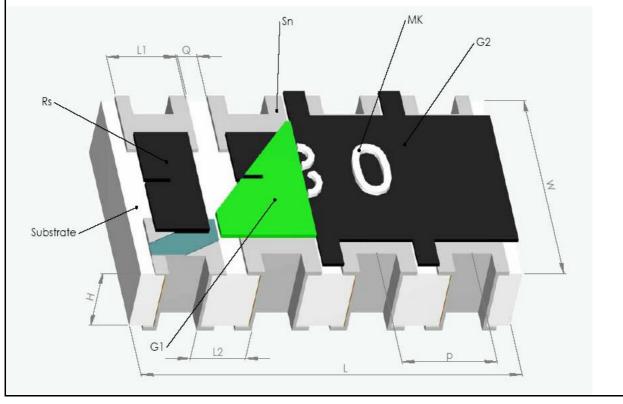
Unit:mm

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5 Reliability Test: 5.1 Electrical Performance Test

		Sne	ecifications	
ITEM	Conditions	Resis		Jumper
Temperature Coefficientof Resistance	TCR (ppm/°C) = $\frac{(R2-R1)}{R1 (T2-T1)} \times 10^6$ R1: Resistance at room temperature R2: Resistance at -55°C or +125°C T1: Room temperature T2: Temperature -55°C or +125°C Refer to JIS-C5201-1 4.8	Refer item 3. Ge Specifications		NA
Short Time Overload	Applied 2.5 times rated voltage for 5 seconds and release the load for about 30 minutes, then measure its resistance variance rate. (Rated voltage refer to item 3. general specifications)	0.5% \ 1%:± (1.0 2% \ 5% :± (2.0)	$\%+0.10\Omega)$	50mΩ Lower
	Refer to JIS-C5201-1 4.13	No evidence of n	nechanicai dam	aye,
Insulation Resistance	Put the resistor in the fixture, add 100 VDC in + ,- terminal for 60 sec then measured the insulation resistance between electrodes and insulating enclosure or between electrodes and base material. Refer to JIS-C5201-1 4.6 Metal black measuring plate Pressurizing by spring Insulating enclosure surface R0.5mm			
Dielectric Withstand Voltage	Put the resistor in the fixture, add 300 VAC in +,- terminal for 60 sec. Refer to JIS-C5201-1 4.7	No short or burne	ed on the appea	irance.
Intermittent	Put the tested resistor in chamber under temperature $25\pm~2^{\circ}$ C and load 2.5 times rated DC voltage for 1 sec on , 25 sec off , 10000^{+400}_{0} test cycles, then it be left at no-load for 1 hour , then measure its resistance variance rate. Refer to JIS-C5201-1 4.13	± (5.0%+0.10Ω	2)	50m Ω Lower
Noise Level	Refer to JIS-C5201-1 4.12	Resistance	Noise	NA
		$\begin{array}{c} R < 100\Omega \\ \\ 100\Omega \leq R < 1K\Omega \\ \\ 1K\Omega \leq R < 10K\Omega \\ \\ 10K\Omega \leq R < 100K\Omega \\ \\ 100K\Omega \leq R < 1M\Omega \\ \\ 1M\Omega \leq R \end{array}$	\leq -10db(0.32 uV/V) \leq 0db(1.0 uV/V) \leq 10db(3.2 uV/V) \leq 15db(5.6 uV/V) \leq 20db(10 uV/V) \leq 30db(32 uV/V)	

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5.2 Mechanical Performance Test

5.2 Mechanical Performance Test						
ITEM	ITEM		Conditions		Specifications	
I I EIVI					Resistors	Jumper
					01-2D:± (1.0%+0.05Ω)	50m Ω
				esistor is left in the	Other:± (0.5%+0.05Ω)	Lower
		tor 48 hr, then	measure its i	resistance variance	No evidence of mechanical dam	
	rate.	to JIS-C5201-1	1 20		G2 overcoating and Sn layer by	ieacning.
		st method 1 (Re			± (1.0%+0.05Ω)	50m Ω
soldering heat				bject in the following	(1.070.0.00.22)	Lower
coldoning node				step, it should be left		Lower
				r at a temperature of	No evidence of electrode damage	je.
		or lower and a	humidity of 7	70% RH or lower.	No side conductive peel off.	
	Step	Procedure	Environr	nental test condition		
	1	Resistance measuring	Room temperat	ure		
	2	Baking	125℃ [,] 24 hou	ırs		
	3	Humidification	85℃,85%,16	68 hours		
	4		Reflow tempera surface tempera	ature curve and component ature Table 1		
	5	Humidification	85℃,65%,24	4 hours		
	6		Reflow tempera surface tempera	ature curve and component ature Table 2		
	7	Resistance measuring	Room temperat	ure		
	⊚Reflow temperature curve					
	Temperature(♥)	50 180°C 50 150°C 50 50	Heating time	D± 10 S Soldering Zone		
	©Component surface temperature Table 1 Description example in specification document(1)					
	time	perature-retaining :230°C or higher	temperature	Temperature measured at the component body surface during preheating		
		30 seconds	240℃	150 to 160 ℃		

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1777			0 ""		Specifications	
ITEM	Conditions			Resistors	Jumper	
	Table 2 Description example in specifi document(2)			specification		'
	Temp	perature Temp	erature-retaining time	Temperature measured at the component body surface during preheating		
	230°C or higher 6		90 seconds 60 seconds 5 seconds 245°C	150 to 160℃		
Test method 2 (sloder pot test): The tested resistor should be subject in the following procedure, and after finish each step, it should be left for a duration of 2 hours or lower at a temperature of 30°C or lower and a humidity of 70% RH or lower. Step Procedure Environmental test condition Resistance measuring Room temperature 2 Baking 125°C → 24 hours 3 Humidification 85°C → 85% → 168 hours 4 Sloder pot test 260± 3°C → 10 sec 5 Placed 85°C → 65% → 24 hours 6 Sloder pot test 260± 3°C → 10 sec 7 Resistance measuring Room temperature By Sony (SS-00254-5) Refer to JIS-C5201-1 4.18		1.Test item 1:				
Soluerability	Preconditioning: Put the tested resistor in the apparatus of PCT, at a temperature of 105°C, humidity of 100% RH, and pressure of 1.22× 10⁵ Pa for a duration of 4 hours. Then after left the tested resistor in room temperature for 2 hours or more. Test method: Test item 1 (solder pot test): The resistor be immersed into solder pot in temperature 235± 5°C for 2 sec, then the resistor is left as placed under microscope to observed its solder area. By SONY (SS-00254-2) Refer to JIS-C5201-1 4.17			Solder coverage over 95%		

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_		Charifications	
ITEM	Conditions	Specifications Resistors	
loint strength	Preconditioning:		•
Joint strength of solder	Preconditioning: Put the tested resistor in the apparatus of PCT, at a temperature of 105°C, humidity of 100% RH, and pressure of 1.22× 10 ⁵ Pa for a duration of 4 hours. Then after left the tested resistor in room temperature for 2 hours or more. Test method: Test item 1 (Adhesion): A static load using a R0.5 scratch tool shall be applied on the core of the component and in the direction of the arrow and held for 10 seconds and under load measure its resistance variance rate. 1.02-2C=10N load 2.Other=20N load Cross-sectional view Scratching jig	Resistors Test item1: 1. △R%=± (1.0%+0.05Ω) 2.No evidence of mechanical damage. No terminal peel off. Test item2: 1. △R%=± (1.0%+0.05Ω) 2.No evidence of mechanical damage. No terminal peel off and core body cracked. Test item3: (1).Adhesion After application of temperature cycle, adhesion should be 50% or more of initial strength. (2).Bending Strength: After application of temperature cycle, bending load should be 50% or more of initial strength.	
	OHM Meter		ļ

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	ì			
ITEM	Conditions		Specifications	
11 - 111			Resistors	Jumper
	○Test item 3 (Endurance measurement): Put the tested resistor in the chamber under the temperature cycle which shown in table 1 shall be repeated 1000± 4 times consecutively. Then separate follow test item 1 and test item 2 50% condition to test, measured its resistance variance rate. Table 1 Temperature cycle test condition			
	Table 1 Temperature cycle	Testing condition		
	Lowest temperature	, , ,		
	Highest temperature	105± 5℃		
	Temperature-retaining time	15 minutes each		
	By SONY (SS-00254-9)			
Leaching Test The tested resistor be immersed into molten solder of 260± 5°C for 30 seconds. Then the resistor is left as placed under microscope to observed its solder area. By SONY (SS-00254-9)		1.Solder coverage over 95%. 2.The underlying material (such ceramic) shall not be visible at the corner area of the electrode.		

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5.3 Environmental Test

5.3 Environmental Test					
ITEM	Conditions		Specifications		
				Resistors	Jumper
Resistance to Dry Heat	for 1,000± 4 hours. Then leaving in room temperature for 60 minutes, and measure its resistance variance rate		0.5% \ 1%:± (1.0%+0.05Ω) 2% \ 5%:± (2.0%+0.10Ω)	50m Ω Lower	
	Refer to JIS-C5201-1 4.25			No evidence of mechanical damage, No evidence of mechanical.	
Thermal Shock	Put the tested resistor in the thermal shock chamber under the temperature cycle which shown in the following table shall be		\pm (1.0%+0.05 Ω) No evidence of mechanical damage	50mΩ Lower	
		Те	esting Condition		
	Lowest Temperature		-55± 5℃		
	Highest Temperature		125± 5℃		
	Temperature-retaining time	1	5 minutes each		
	Refer to MIL-STD 202 Method 107				
Loading Life in Moisture	Put the tested resistor in the chamber under temperature $40\pm$ 2° C, relative humidity $90{\sim}95\%$ and load the rated voltage for 90			$0.5\% \cdot 1\%$:± $(2.0\% + 0.10\Omega)$	50m Ω Lower
Moisture	minutes on, 30 minutes off, total 1000			No evidence of mechanical damage	
	tested resistor in room temperature for				
	measure its resistance variance rate.				
Load Life	Refer to JIS-C5201-1 4.24			0.5% \ 1%:± (2.0%+0.10Ω)	50 m Ω
Load Lile		Put the tested resistor in chamber under temperature $70\pm~2^{\circ}$ C and load the rated voltage for 90 minutes on, 30 minutes off,		$2\% \cdot 5\% : \pm (3.0\% + 0.10\Omega)$	Lower
	total 1000 hours. Then leaving the tes			No evidence of mechanical	_5,,,
	temperature for 60 minutes, and mea			damage, no short or burned on the	
	variance rate.			appearance.	
Low		Refer to JIS-C5201-1 4.25 Put the tested resistor in the chamber at room temperature		0.5% \ 1%:± (0.5%+0.05Ω)	50m Ω
Temperature	25°C. Decreasing the temperature to			2% \ 5% :± (1.0% +0.05Ω)	Lower
Operation	temperature at -55°C for 1 hour. The	n load	d the rated voltage	No evidence of mechanical damage	9,
	for 45 minutes on, and 15 minutes off				
	resistor in room temperature for 8± 1 resistance variance rate.	nour	s, and measure its		
	Refer to MIL-R-55342D 4.7.4				
Whisker Test				Max. 50 μ m	
	Minimum storage temperatu		-40± 2°C		
		Maximum storage temperature 85± 2			
		Temperature-rataining time 7 min.			
	Number of temperature cycl	-			
	Test item 2 (Constant temperature/				
	Temperature		85℃		
	Humidity		85%		
	Testing duration	500± 4 hours			
I					

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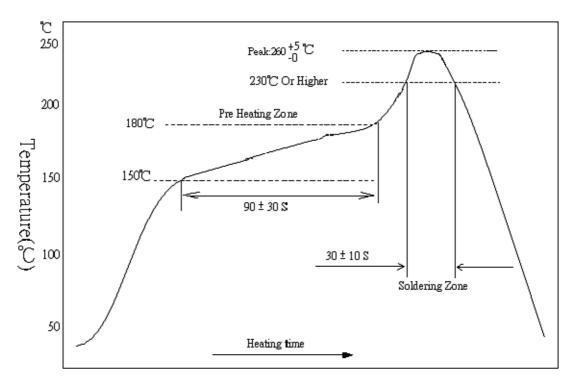
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ITEM	Conditions	Specifications		
I I ⊑IVI	Conditions	Resistors	Jumper	
	⊙Inspection: Inspect for whisker formation on specimens that underwent the acceleration test specified in subciause 4.2, with a magnifier (stereomicroscope) of about 40 or higher magnification. If judgment is hard in this method, use a scanning electron micro- scope (SEM) of about 1,000 or higher magnification. By SONY (SS-00254-8)			

6 Recommend Soldering Method

6.1 Lead Free Reflow Soldering Profile



6.2 Soldering Iron: temperature 350 $^\circ\!\!\!\!C^\pm$ 10 $^\circ\!\!\!\!C$, dwell time shall be less than 3 sec.

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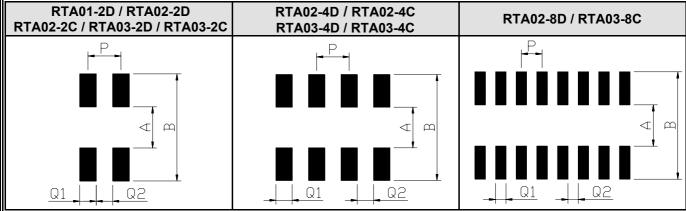
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7 Recommend Land Pattern Design (For Reflow Soldering):

Unit: mm



TYPE DIM	Α	В	Р	Q1	Q2
RTA01-2D	0.30	0.90	0.50	0.30	0.30
RTA02-2D	0.50	2.00	0.67	0.33	0.34
RTA03-2D	1.00	2.60	0.80	0.40	0.40
RTA02-4D RTA02-4C	0.50	2.00	0.50	0.28	0.22
RTA03-4D RTA03-4C RTA03-2C	1.00	2.60	0.80	0.40	0.40
RTA02-8D	1.00	2.60	0.50	0.25	0.25
RTA03-8C	1.00	2.60	0.80	0.40	0.40
RTA02-2C	0.50	2.00	0.50	0.28	0.22

8 Marking Diagrams:

- 8.1 \pm 2% \cdot \pm 5% Tolerance:
 - 8.1.1 Resistance Range \geq 10 Ω : 3 digits in E-24 series, first two digits are significant figures, third digit is is multiplier (10 $^{\times}$).

$$\langle EX \rangle$$
 Marking→100
100=10 × 10⁰ =10 Ω

8.1.2 Resistance Range < 10 Ω : 3 digits in E-24 series, first and thrid digits are significant figures, second digit is multiplier (10-1).

$$\langle EX \rangle$$
 Marking→4R7
4R7=47× 10⁻¹ =4.7Ω

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- 8.2 ± 0.5% \ 1% Tolerance:
 - 8.2.1 Resistance Range \geq 100 Ω : 4 digits in E-24 series or E-96 series, first three digits are significant figures, forth digit is multiplier (10 $^{\times}$).

1002=100
$$\times$$
 10²=10000 Ω =10K Ω

8.2.2 Resistance Range < 100 Ω : 4 digits in E-24 series or E-96 series, three digits are significant figures,R digit is multiplier (10 $^{\times}$).

$$\langle\!\langle EX \rangle\!\rangle$$
 Marking \rightarrow 10R2 ,R digit is multiplier (10-1).

$$10R2 = 102 \times 10^{-1} = 10.2 \Omega$$

$$1R02 = 102 \times 10^{-2} = 1.02 \Omega$$

8.3 RTA01-2D \ RTA02-2D \ RTA02-2C \ RTA02-4C No Marking

8.4 Marking Standard

Standard TYPE Marking	1	2	3	4	5	6	7	8	9	0	R
RTA03-2D RTA02-4D RTA03-2C RTA03-4D RTA03-4C RTA02-8D RTA03-8C	-	2	3	J	5	6	7	S	9	0	R

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8.5 Marking

8.5.1 E-24 series

10	11	12	13	15	16	18	20	22	24	27	30
33	36	39	43	47	51	56	62	68	75	82	91

8.5.2 E-96 series

100	102	105	107	110	113	115	118	121	124	127	130
133	137	140	143	147	150	154	158	162	165	169	174
178	182	187	191	196	200	205	210	215	221	226	232
237	243	249	255	261	267	274	280	287	294	301	309
316	324	332	340	348	357	365	374	383	392	402	412
422	432	442	453	464	475	487	499	511	523	536	549
562	576	590	604	619	634	649	665	681	698	715	732
750	768	787	806	825	845	866	887	909	931	953	976

9 Plating Thickness:

9.1 Ni: ≥1 µ m

9.2 Sn(Tin): $\ge 3 \mu m$ 9.3 Sn(Tin): Matte Sn

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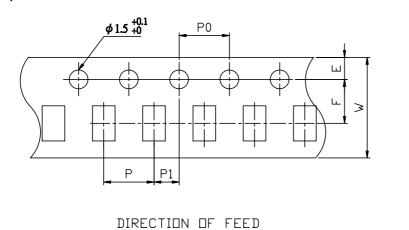
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10 Taping Specifications

10.1Tape Dimension



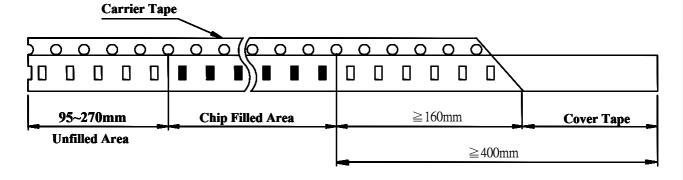
TAPE

CARRIER

Unit: mm

Packaging	DIM Type	Α	В	W	E	F	T1	Т2	Р	P0	10× P0	P1
	RTA01-2D	0.90± 0.1	0.70± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.45+0.2/-0	0.43± 0.1	2.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
TH	RTA02-2D	1.20± 0.1	1.20± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.45+0.2/-0	0.43± 0.1	2.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
Carrier	RTA02-2C	1.20± 0.1	1.20± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.45+0.2/-0	0.43± 0.1	2.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
Tape	RTA02-4D	2.20± 0.1	1.20± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.60+0.2/-0	0.60± 0.1	2.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
Tape	RTA02-4C	2.20± 0.1	1.20± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.60+0.2/-0	0.60± 0.1	2.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
TD	RTA03-2D	1.90± 0.1	1.90± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.60+0.2/-0	0.60± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
TP	RTA03-4D	3.45± 0.1	1.90± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.75+0.2/-0	0.75± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
Carrier	RTA03-4C	3.45± 0.1	1.90± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.75+0.2/-0	0.75± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
Tape	RTA02-8D	4.30± 0.2	1.90± 0.2	12.0± 0.2	1.75± 0.1	5.5± 0.05	0.60+0.2/-0	0.60± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
	RTA03-8C	6.90± 0.2	2.00± 0.2	12.0± 0.2	1.75± 0.1	5.5± 0.05	0.75+0.2/-0	0.75± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05
	RTA03-2C	1.90± 0.1	1.90± 0.1	8.0± 0.2	1.75± 0.1	3.5± 0.05	0.75+0.2/-0	0.75± 0.1	4.0± 0.1	4.0± 0.05	40.0± 0.20	2.0± 0.05

10.2Lead Dimensions:



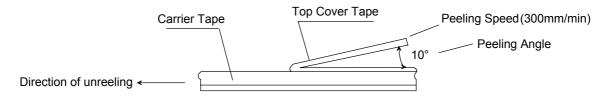
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10.3Cover Tape Peel off Strength Specifications:0.07~0.7N (7.1~71.4gf)



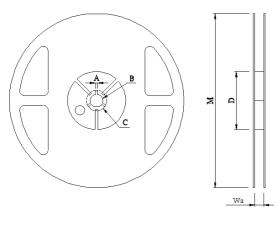
10.4Packaging Qty:

U.4Fackaging Qty.											
		Packaging (pcs/reel)									
Time	Tape		ТН				TP				
Type	Width	2 mm Pitch					4 mm	Pitch			
		TH	H2	Н3	H4	TP	P2	P2	P4		
RTA01-2D	8 mm										
RTA02-2D \ RTA02-2C	8 mm	10,000	20,000	30,000	40,000						
RTA02-4C \ RTA02-4D	8 mm										
RTA03-2D \ RTA03-2C	8 mm										
RTA03-4C \ RTA03-4D	8 mm]				5,000	10,000	15,000	20,000		
RTA02-8D \ RTA03-8C	12 mm										
Reel Type		7"	10"	13"	13"	7"	10"	13"	13"		

10.4.1Typical taping type: TH ⋅ TP

10.4.20ther taping type are upon customer's request.

10.5Reel Dimensions:



					Unit:m	nm
Reel Type / Tape	Wa	M	A	В	С	D
7" reel for 8 mm tape	9.0 ± 0.5	178 ± 2.0				60.0 ± 1.0
7" reel for 12 mm tape	13.8 ± 0.5	178 ± 2.0	2.0	13.5	21.0 ± 0.5	80.0 ± 1.0
10" reel for 8 mm tape	10.0 ± 0.5	254 ± 2.0	± 0.5	± 0.5		100.0 ± 1.0
13" reel for 8 mm tape	10.0 ± 0.5	330 ± 2.0				100.0 ± 1.0

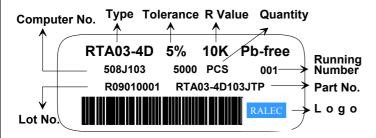
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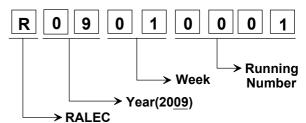
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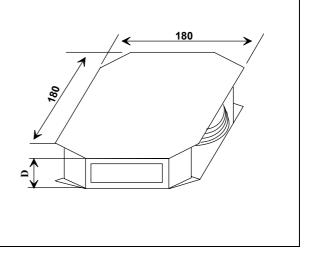
10.6Label:





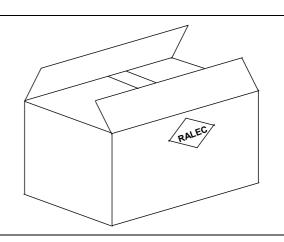
10.7Inner Box

Reel Number	D Dimension (mm)
1	12
2	24
3	36
4	48
5	60
6	72
7	84
8	96
9	108
10	120



10.8Box

10R Inner Box Number	L(mm)	W(mm)	D(mm)
2	272	205	210
4	375	280	210
8	544	380	210



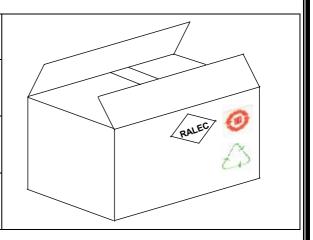
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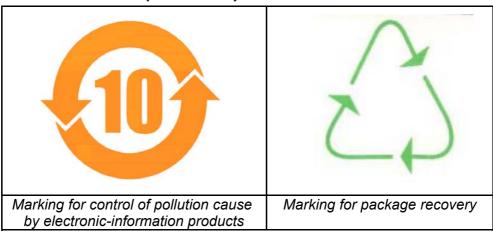
10.9Box (For China)

10R Inner BoxNumber	L(mm)	W(mm)	D(mm)
2	272	205	210
4	375	280	210
8	544	380	210



11 Stock period

12 The carton packaged for electronic-information products is made by the symbol as follows: (For china)



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- 13 For this part. It does not use the materials that include the substances specified in RoHS, the detail refer to the part of prohibition or exclusion items in RoHS (2002/95/EC).
 - 1. Cadmium and cadmium compounds (permissive content < 100 ppm)
 - 2. Lead and lead compounds *(permissive content < 1000 ppm)* Exceptions specified:
 - (1). Lead contained in the glass of cathode ray tubes, electronic components and fluorescent tubes.
 - (2). The glass material used in the electronic components, which includes resistor elements, conductive pastes (silver or copper ones), adhesives, glass frit and sealing materials.
 - 3. Mercury and its mercury compounds (permissive content < 100 ppm)
 - 4. Hexavalent chromium compounds (permissive content < 100 ppm)
 - 5. Polybrominated biphenyls(PBB) (permissive content < 100 ppm)
 - 6. Polybrominated diphenylethers(PBDE) (permissive content < 100 ppm)

14 Attachments

14.1Document Revise Record Paper

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